

4-bit Single Chip Microcomputer



- Core CPU Architecture
- SVD Circuit
- DTMF/DP Generator
- High Quality Display LCD Driver

■ DESCRIPTION

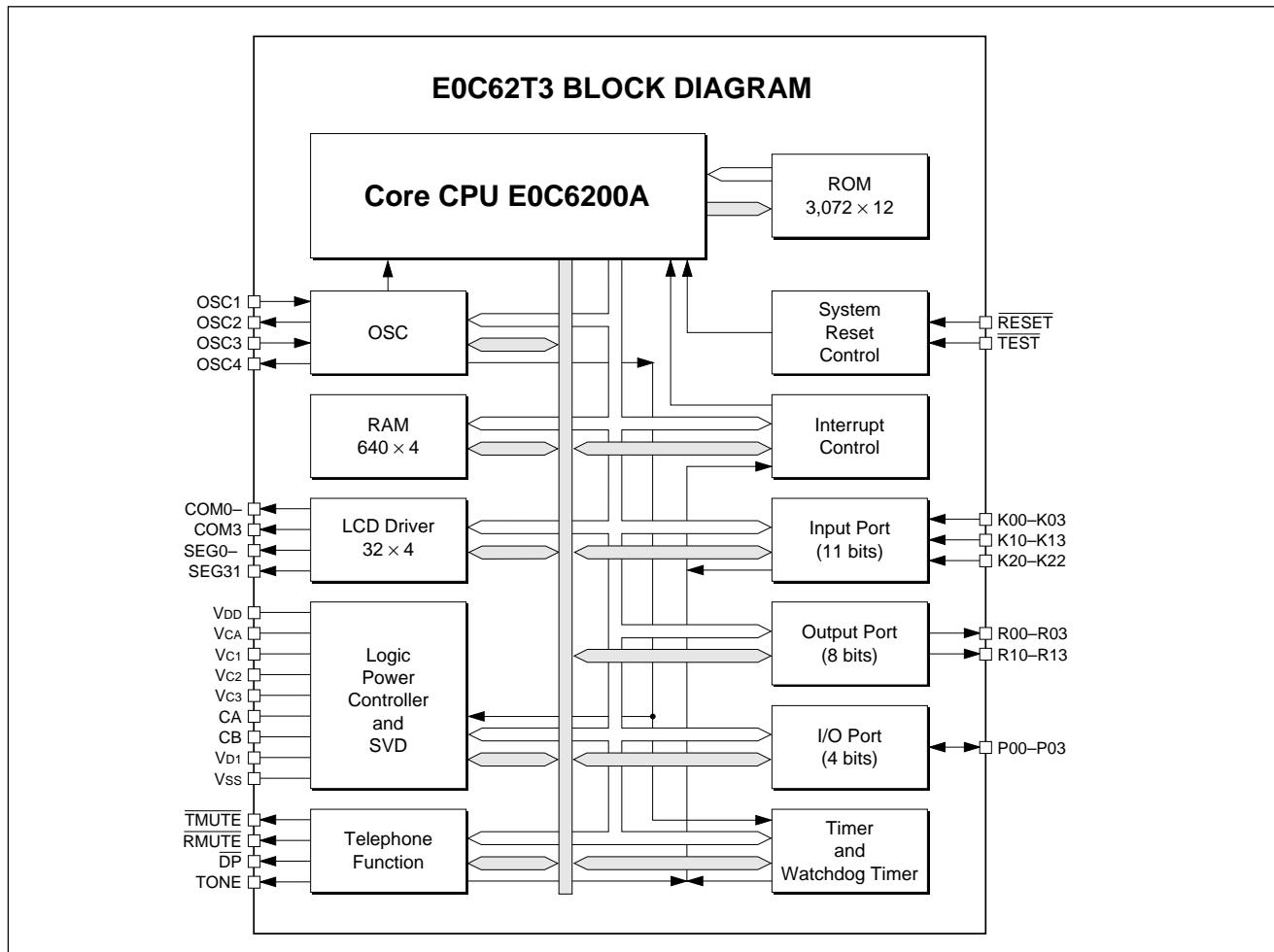
The E0C62T3 is a single-chip microcomputer made up of the 4-bit core CPU E0C6200A, ROM, RAM, LCD driver, watchdog timer, time base counter, SVD circuit and DTMF/DP generator. The E0C62T3 can be applied to telephone set which has feature as DTMF/DP switchable, repertory dial, ON/OFF hook dial, etc.

■ FEATURES

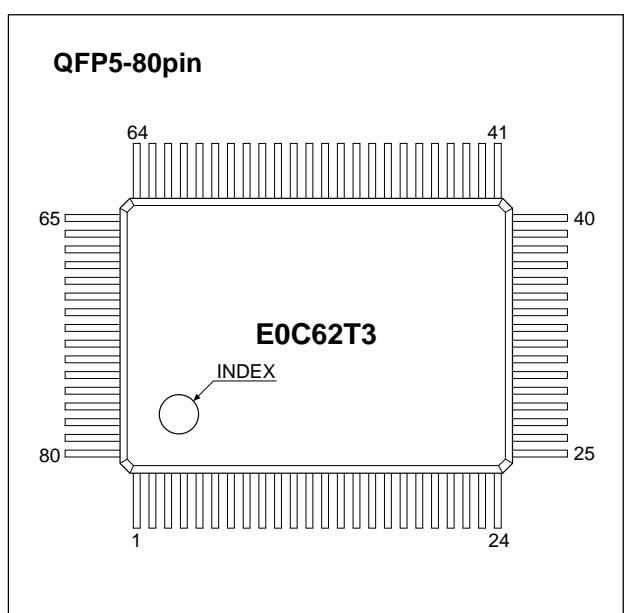
- CMOS LSI 4-bit parallel processing
- Twin clock OSC1 : Crystal oscillation circuit 32.768kHz (Typ.)
OSC3 : Crystal or ceramic oscillation circuit
(selected by mask option) 3.579545MHz (Typ.)
- Instruction set 108 instructions
- Instruction execution time During operation at 32kHz : 153μsec, 214μsec, 366μsec
(depending on instruction) During operation at 3.58MHz : 11.1μsec, 15.6μsec, 26.7μsec
- ROM capacity 3,072 words × 12 bits
- RAM capacity 640 words × 4 bits
- Input port 11 bits (pull-up resistors are available by mask option)
- Output port 8 bits (buzzer, hold-line and handfree output are available by software control)
- I/O port 4 bits (pull-up resistors are available by software control)
- LCD driver 32 segments × 4, 3, 2 or 1 commons (can be selected by software)
Voltage regulator and booster circuits built-in
(compatible with 3–4.5V LCD, VR adjustable)
- Built-in DTMF generator
- Built-in DP generator
- Built-in time base counter
- Built-in watchdog timer
- Supply voltage detection (SVD) circuit .. 1.8V
- Built-in stopwatch timer
- Interrupts External : Input port interrupt 4 systems
Internal : Timer interrupt 1 system
Dialing interrupt 1 system
- Supply voltage 1.6V to 5.5V (32kHz)
2.5V to 5.5V (OSC3 = ON, DTMF)
- Current consumption (Typ.) HALT mode (32kHz/3.0V) : 2.0μA
OPERATING mode (32kHz/3.0V) : 5.0μA
OPERATING mode (3.58MHz/3.0V) : 200μA
DTMF operating (3.58MHz/3.0V) : 1.3mA
- Package QFP5-80pin / QFP14-80pin (plastic)
Die form

E0C62T3

■ BLOCK DIAGRAM



■ PIN CONFIGURATION



Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name
1	SEG14	21	P02	41	R12	61	Vc3
2	SEG15	22	P03	42	R13	62	Vc2
3	SEG16	23	TEST	43	RESET	63	COM0
4	SEG17	24	K00	44	Vdd	64	COM1
5	SEG18	25	K01	45	RMUTE	65	COM2
6	SEG19	26	K02	46	TMUTE	66	COM3
7	SEG20	27	K03	47	DP	67	SEG0
8	SEG21	28	K10	48	Vss	68	SEG1
9	SEG22	29	K11	49	OSC1	69	SEG2
10	SEG23	30	K12	50	OSC2	70	SEG3
11	SEG24	31	K13	51	OSC3	71	SEG4
12	SEG25	32	K20	52	OSC4	72	SEG5
13	SEG26	33	K21	53	Vd1	73	SEG6
14	SEG27	34	K22	54	TONE	74	SEG7
15	SEG28	35	R00	55	N.C.	75	SEG8
16	SEG29	36	R01	56	N.C.	76	SEG9
17	SEG30	37	R02	57	CA	77	SEG10
18	SEG31	38	R03	58	CB	78	SEG11
19	P00	39	R10	59	Vc1	79	SEG12
20	P01	40	R11	60	Vca	80	SEG13
N.C. : No Connection							

QFP14-80pin

Pin No.	Pin Name						
1	N.C.	21	COM0	41	SEG16	61	TEST
2	RESET	22	COM1	42	SEG17	62	K00
3	VDD	23	COM2	43	SEG18	63	K01
4	RMUTE	24	COM3	44	SEG19	64	K02
5	TMUTE	25	SEG0	45	SEG20	65	K03
6	DP	26	SEG1	46	SEG21	66	K10
7	Vss	27	SEG2	47	SEG22	67	K11
8	OSC1	28	SEG3	48	SEG23	68	K12
9	OSC2	29	SEG4	49	SEG24	69	K13
10	OSC3	30	SEG5	50	SEG25	70	K20
11	OSC4	31	SEG6	51	SEG26	71	K21
12	VD1	32	SEG7	52	SEG27	72	K22
13	TONE	33	SEG8	53	SEG28	73	R00
14	N.C.	34	SEG9	54	SEG29	74	R01
15	CA	35	SEG10	55	SEG30	75	R02
16	CB	36	SEG11	56	SEG31	76	R03
17	Vc1	37	SEG12	57	P00	77	R10
18	VCA	38	SEG13	58	P01	78	R11
19	Vc3	39	SEG14	59	P02	79	R12
20	Vc2	40	SEG15	60	P03	80	R13

N.C. : No Connection

■ PIN DESCRIPTION

Pin name	Pin No.		I/O	Function
	QFP5-80	QFP14-80		
VDD	44	3		Power supply (+)
Vss	48	7		Power supply (-)
VD1	53	12	O	Internal logic system regulated voltage output terminal
VCA	60	18	I	LCD system voltage adjustment terminal
Vc1	59	17	O	LCD system regulated voltage output terminal
Vc2	62	20	O	LCD system booster voltage output terminal (Vc1×2)
Vc3	61	19	O	LCD system booster voltage output terminal (Vc1×3)
CA, CB	57, 58	15, 16	-	LCD system voltage booster capacitor connecting terminals
OSC1	49	8	I	32.768kHz crystal oscillator input terminal
OSC2	50	9	O	32.768kHz crystal oscillator output terminal
OSC3	51	10	I	3.58MHz crystal or ceramic oscillator input terminal (selected by mask option)
OSC4	52	11	O	3.58MHz crystal or ceramic oscillator output terminal (selected by mask option)
K00-K03	24-27	62-65	I	Input terminals
K10-K13	28-31	66-69	I	Input terminals
K20-K22	32-34	70-72	I	Input terminals
P00-P03	19-22	57-60	I/O	I/O terminals (at input mode, pull-up resistors are selected by software)
R00-R03	35-38	73-76	O	Output terminals
R10-R13	39-42	77-80	O	Output terminals (buzzer, hold-line and handfree are selected by software)
SEG0-SEG31	67-18	25-56	O	LCD segment output terminals (DC output is selected by mask option)
COM0-COM3	63-66	21-24	O	LCD common output terminals (1/4, 1/3, 1/2, 1/1 duty programmable)
RESET	43	2	I	Initial setting input terminal
TEST	23	61	I	Test input terminal
RMUTE	45	4	O	Receiver mute output terminal
TMUTE	46	5	O	Transmitter mute output terminal
DP	47	6	O	Dialing pulse output terminal
TONE	54	13	O	DTMF output terminal

E0C62T3

■ ELECTRICAL CHARACTERISTICS

● Absolute Maximum Ratings

Rating	Symbol	Value	(Vss=0V)
Supply voltage	VDD	-0.5 to 7.0	V
Input voltage (1)	VI	-0.5 to VDD + 0.3	V
Input voltage (2)	VIOSC	-0.5 to VD1 + 0.3	V
Permissible total output current *1	ΣI_{VDD}	10	mA
Operating temperature	Topr	-20 to 70	°C
Storage temperature	Tstg	-65 to 150	°C
Soldering temperature / Time	Tsol	260°C, 10sec (lead section)	—
Permissible dissipation *2	PD	250	mW

*1: The permissible total output current is the sum total of the current (average current) that simultaneously flows from the output pins (or is drawn in).

*2: In case of plastic package (QFP5-80pin, QFP14-80pin).

● Recommended Operating Conditions

Condition	Symbol	Remark	Min.	Typ.	Max.	Unit
Supply voltage	VDD	Vss=0V, OSC1=32kHz, OSC3=stop	1.6	3.0	5.5	V
		Vss=0V, when DTMF is used	2.5		5.5	V
Oscillation frequency (1)	fosc1			32.768		kHz
Oscillation frequency (2)	fosc3			3.579545		MHz

● DC Characteristics

(Unless otherwise specified: Vss=0V, VDD=3.0V, fosc1=32.768kHz, Ta=25°C, VD1/Vc1–Vc3 are internal voltage, C1–C5=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
High level input voltage (1)	VIH1	K00–K03, K10–K13, K20–K22 P00–P03	0.8·VDD		VDD	V
High level input voltage (2)	VIH2	RESET, TEST	0.9·VDD		VDD	V
Low level input voltage (1)	VIL1	K00–K03, K10–K13, K20–K22 P00–P03	0		0.2·VDD	V
Low level input voltage (2)	VIL2	RESET, TEST	0		0.1·VDD	V
High level input current (1)	I _{IH1}	VIH1=3.0V No pull-up resistor	K00–K03, K10–K13, K20–K22 P00–P03	0		0.5 μA
High level input current (2)	I _{IH2}	VIH2=3.0V With pull-up resistor	K00–K03, K10–K13, K20–K22 P00–P03, RESET, TEST			0.5 μA
Low level input current (1)	I _{IL1}	VIL1=Vss No pull-up resistor	K00–K03, K10–K13, K20–K22 P00–P03, RESET, TEST	-0.5		0 μA
Low level input current (2)	I _{IL2}	VIL2=Vss With pull-up resistor	K00–K03, K10–K13, K20–K22 P00–P03, RESET, TEST	-20	-10	-5 μA
High level output current (1)	I _{OH1}	V _{OH1} =0.9·VDD	R00–R03, R10–R13, P00–P03			-1 mA
High level output current (2)	I _{OH2}	V _{OH2} =0.9·VDD	DP, TMUTE, RMUTE			-1 mA
Low level output current (1)	I _{OL1}	V _{OL1} =0.1·VDD	R00–R03, R10–R13, P00–P03	3		mA
Low level output current (2)	I _{OL2}	V _{OL2} =0.1·VDD	DP, TMUTE, RMUTE	3		mA
Common output current	I _{OH3}	V _{OH3} =Vc3-0.05V	COM0–COM3			-3 μA
	I _{OL3}	V _{OL3} =Vss+0.05V		3		μA
Segment output current (during LCD output)	I _{OH4}	V _{OH4} =Vc3-0.05V	SEG0–SEG31			-3 μA
	I _{OL4}	V _{OL4} =Vss+0.05V		3		μA
Segment output current (during DC output)	I _{OH5}	V _{OH5} =0.9·VDD	SEG0–SEG31			-300 μA
	I _{OL5}	V _{OL5} =0.1·VDD		300		μA

● Analog Circuit Characteristics and Current Consumption

(Unless otherwise specified: Vss=0V, VDD=3.0V, fosc1=32.768kHz, fosc3=3.579545MHz/crystal, CG=25pF, Ta=25°C, VD1/Vc1–Vc3 are internal voltage, C1–C5=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
LCD drive voltage	Vc1	Connect 1MΩ load resistor between Vss and Vc1 VCA=Vc1, (without panel load)	0.95	1.05	1.15	V
	Vc2	Connect 1MΩ load resistor between Vss and Vc2 (without panel load)	2·Vc1×0.9		2·Vc1+0.1	V
	Vc3	Connect 1MΩ load resistor between Vss and Vc3 (without panel load)	3·Vc1×0.9		3·Vc1+0.1	V
SVD voltage	V _{SVD}		1.65	1.8	1.95	V
SVD circuit response time	t _{SVD}				100	μS
Current consumption	I _{OP}	During HALT (32kHz) During execution (32kHz) *1 During execution (3.58MHz) *1 During execution (3.58MHz) *2	Without panel load	2	5	μA
				5	12	μA
				200	500	μA
				1.3	4	mA

*1: The SVD and DTMF generator are OFF status.

*2: The DTMF generator is ON status. The SVD is OFF status.

● Oscillation Characteristics

The oscillation characteristics change depending on the conditions (components used, board pattern, etc.). Use the following characteristics as reference values.

OSC1 crystal oscillation circuit

(Unless otherwise specified: Vss=0V, VDD=3.0V, Crystal: C-002R, Cl=35kΩ, Cg=25pF, Cd=built-in, Ta=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation start voltage	Vsta	tsta≤3sec (VDD)	1.6			V
Oscillation stop voltage	Vstp	tstp≤10sec (VDD)	1.6			V
Built-in capacitance (drain)	Cd	Including the parasitic capacity inside the IC		18.5		pF
Frequency/voltage deviation	Δf/ΔV	VDD=2.0 to 5.5V			5	ppm
Frequency/IC deviation	Δf/ΔIC		-10		10	ppm
Frequency adjustment range	Δf/ΔCG	Cg=5 to 25pF	35			ppm
Harmonic oscillation start voltage	Vhho	Cg=5pF (VDD)			5.5	V
Permitted leak resistance *	Rleak	Between OSC1 and Vss	200			MΩ

*: The shielding plate for OSC1 and OSC2 should be connected to Vss.

OSC3 crystal oscillation circuit

(Unless otherwise specified: Vss=0V, VDD=3.0V, Crystal: CA-301, Cg=5pF, Cd=built-in, Ta=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation start voltage	Vsta	tsta≤30msec (VDD)	1.6			V
Oscillation stop voltage	Vstp	tstp≤10sec (VDD)	1.6			V
Built-in capacitance (drain)	Cd	Including the parasitic capacity inside the IC		14		pF
Frequency/voltage deviation	Δf/ΔV	VDD=2.0 to 5.5V			5	ppm
Frequency/IC deviation	Δf/ΔIC		-10		10	ppm
Frequency adjustment range	Δf/ΔCG	Cg=5 to 25pF	35			ppm
Harmonic oscillation start voltage	Vhho	Cg=5pF (VDD)			5.5	V
Permitted leak resistance	Rleak	Between OSC3 and VDD, Vss	200			MΩ

OSC3 ceramic oscillation circuit

(Unless otherwise specified: Vss=0V, VDD=3.0V, Ceramic oscillator: 3.579545MHz, Ccc=Cdc=30pF, Rf=1MΩ, Ta=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation start voltage	Vsta		(VDD)	2.0		V
Oscillation start time	tsta				3	mS
Oscillation stop voltage	Vstp		(VDD)	2.0		V

● Telephone Function Characteristics

(Unless otherwise specified: Vss=0V, VDD=3.0V, fosc1=32.768kHz, fosc3=3.579545MHz, Ta=25°C, Vd1/Vc1–Vc3 are internal voltage, C1–C5=0.1μF)

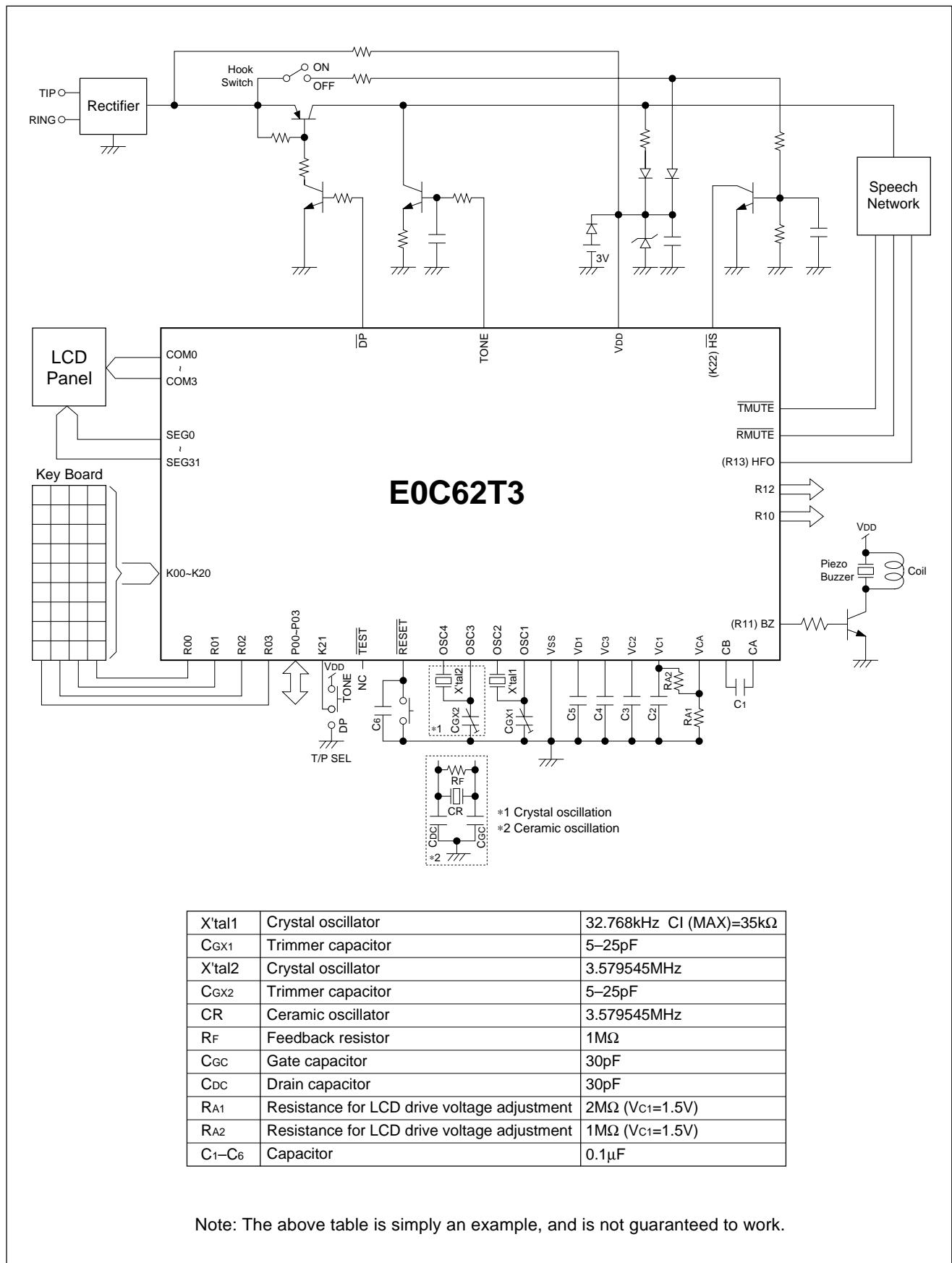
Characteristic	Symbol		Condition				Min.	Typ.	Max.	Unit
			FTS3	FTS2	FTS1	FTS0				
Flash time	tFL		0	0	0	1		94		mS
			0	0	1	0		188		
			0	0	1	1		281		
			0	1	0	0		375		
			0	1	0	1		469		
			0	1	1	0		563		
			0	1	1	1		656		
			1	0	0	0		750		
			1	0	0	1		844		
			1	0	1	0		938		
			1	0	1	1		1031		
			1	1	0	0		1125		
			1	1	0	1		1219		
			1	1	1	0		1313		
			1	1	1	1		1406		
Flash pause time	tFLP							938		mS

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(Unless otherwise specified: Vss=0V, VDD=3.0V, fosc1=32.768kHz, fosc3=3.579545MHz, Ta=25°C, VD1/Vc1–Vc3 are internal voltage, C1–C5=0.1μF)

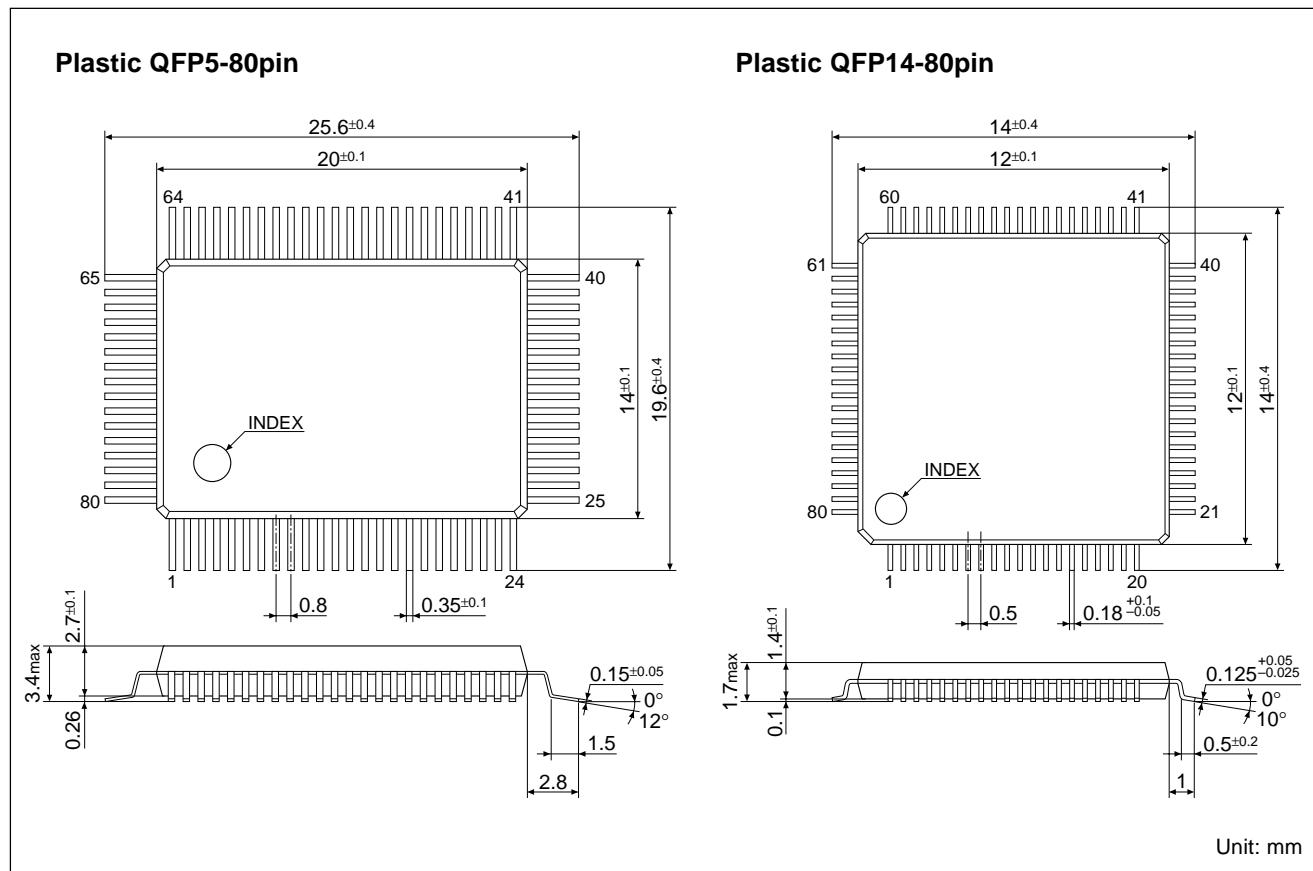
Characteristic	Symbol	Condition				Min.	Typ.	Max.	Unit
Pause time	t_{PS}		PTS3	PTS2	PTS1	PTS0	—		
			0	0	0	1	1		
			0	0	1	0	2		
			0	0	1	1	3		
			0	1	0	0	4		
			0	1	0	1	5		
			0	1	1	0	6		
			0	1	1	1	7		
			1	0	0	0	8		
			1	0	0	1	9		
			1	0	1	0	10		
			1	0	1	1	11		
			1	1	0	0	12		
			1	1	0	1	13		
			1	1	1	0	14		
			1	1	1	1	15		
Mute hold time	t_{MH}						—	4	—
Inter-digit pause time	t_{IDP}		IDP3	IDP2	IDP1	IDP0	—		
			0	0	0	1	94		
			0	0	1	0	188		
			0	0	1	1	281		
			0	1	0	0	375		
			0	1	0	1	469		
			0	1	1	0	563		
			0	1	1	1	656		
			1	0	0	0	750		
			1	0	0	1	844		
			1	0	1	0	938		
			1	0	1	1	1031		
			1	1	0	0	1125		
			1	1	0	1	1219		
			1	1	1	0	1313		
			1	1	1	1	1406		
Make/Break ratio	M/B	Software-selected				—	1/2 2/3	—	—
Dialing pulse rate	DR	Software-selected				—	10 20	—	pps
Make time	t_M	10pps, M/B=1/2				—	33.2	—	mS
		20pps, M/B=1/2				—	16.6	—	
		10pps, M/B=2/3				—	39.1	—	
		20pps, M/B=2/3				—	19.5	—	
Break time	t_B	10pps, M/B=1/2				—	66.4	—	mS
		20pps, M/B=1/2				—	33.2	—	
		10pps, M/B=2/3				—	58.6	—	
		20pps, M/B=2/3				—	29.3	—	
Tone output DC level	V_{TDC}					—	0.5(VDD-Vss)	—	V
Single Row tone output amplitude	VR	$V_{DD}=3V$, $R_L=10k\Omega$				—	92	—	mV_{rms}
		$V_{DD}=5.5V$, $R_L=10k\Omega$				—	168	—	mV_{rms}
Single Column tone output amplitude	Vc	$V_{DD}=3V$, $R_L=10k\Omega$				—	122	—	mV_{rms}
		$V_{DD}=5.5V$, $R_L=10k\Omega$				—	224	—	mV_{rms}
Tone output voltage ratio	dBCR	$V_{DD}=3V$, $R_L=10k\Omega$				—	2.5	—	dB
		$V_{DD}=5.5V$, $R_L=10k\Omega$				—	2.5	—	dB
Tone load impedance	R_{TL}	$V_{DD}=2-5.5V$				7	—	—	$k\Omega$
Total harmonic distortion	THD	$V_{DD}=2-5.5V$, $R_L=10k\Omega$				—	—	6	%
Tone output frequency	fROW1					—	701.32	—	Hz
	fROW2					—	771.45	—	
	fROW3					—	857.17	—	
	fROW4					—	935.10	—	
	fCOL1					—	1215.88	—	
	fCOL2					—	1331.68	—	
	fCOL3					—	1471.85	—	
	fCOL4					—	1645.01	—	
Tone duration time	t_{TD}					94	—	—	mS
Tone inter-digit pause	t_{TIP}					—	94	—	mS
Maximum dial rate	t_T	$t_{TD} + t_{TIP}$					188	—	mS

■ BASIC EXTERNAL CONNECTION DIAGRAM



E0C62T3

■ PACKAGE DIMENSIONS



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